

PATENT ASSIGNMENT COVER SHEET

Electronic Version v1.1
Stylesheet Version v1.2

EPAS ID: PAT4629028

SUBMISSION TYPE:	NEW ASSIGNMENT
NATURE OF CONVEYANCE:	ASSIGNMENT
CONVEYING PARTY DATA	
Name	Execution Date
HAMZA YILMAZ	01/10/2012
ANUP BHALLA	01/30/2012
YEEHENG LEE	01/30/2012
DANIEL NG	01/31/2012
JONGOHO KIM	01/31/2012
JI PAN	02/01/2012
DANIEL CALAFUT	02/01/2012
MADHUR BOBDE	02/02/2012
RECEIVING PARTY DATA	
Name:	ALPHA AND OMEGA SEMICONDUCTOR INCORPORATED
Street Address:	475 OAKMEAD PARKWAY
City:	SUNNYVALE
State/Country:	CALIFORNIA
Postal Code:	94085
PROPERTY NUMBERS Total: 1	
Property Type	Number
Application Number:	15680712
CORRESPONDENCE DATA	
Fax Number:	(510)668-0239
<i>Correspondence will be sent to the e-mail address first; if that is unsuccessful, it will be sent using a fax number, if provided; if that is unsuccessful, it will be sent via US Mail.</i>	
Phone:	510-668-0965
Email:	josh@jdipatent.com
Correspondent Name:	JOSHUA D. ISENBERG
Address Line 1:	809 CORPORATE WAY
Address Line 4:	FREMONT, CALIFORNIA 94539
ATTORNEY DOCKET NUMBER:	ANO-049/DIV/CON2
NAME OF SUBMITTER:	JOSHUA D. ISENBERG
SIGNATURE:	/Joshua D. Isenberg, Reg. No. 41088/

DATE SIGNED:	10/05/2017
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Total Attachments: 8

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- source=ANO-049_DIV_CON2_Signed_Assignment#page2.tif
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ASSIGNMENT

**INVENTOR
AND CITY**

Whereas, I, **HAMZA YILMAZ** of 20755 Trinity Avenue
Saratoga, CA 95070, USA

have invented:

TITLE:

**NANO MOSFET WITH TRENCH BOTTOM OXIDE SHIELDED
AND THIRD DIMENSIONAL P-BODY CONTACT**

**DATE INVENTOR
SIGNED THE
DECLARATION**

and executed a United States patent application therefor

on _____, 2012 Said assignor hereby authorize and request
their attorney, Joshua D. Isenberg, of 809 Corporate Way, Fremont,
California. to insert here in parentheses (Application number
15/680,712, filed August, 18, 2017) the filing
date and application number of said application when known.

Whereas, **Alpha and Omega Semiconductor Incorporated**, a
California Corporation, having its registered address at 475 Oakmead
Pkwy, Sunnyvale, CA 94085, (hereinafter called **AOS**), desires to acquire
the entire right, title and interest of said application and invention, and to
any United States and foreign patents to be obtained therefore;

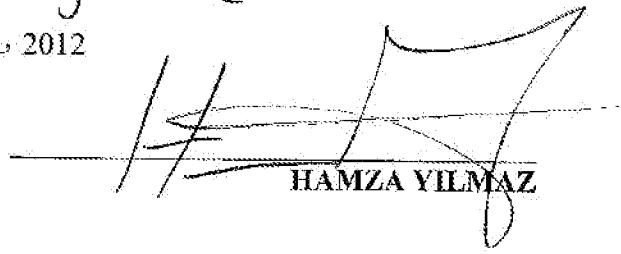
Now therefore for a valuable consideration, receipt whereof is
hereby acknowledged, I, the above named, hereby sell, assign, and transfer
to **AOS**, its successors and assigns, the entire right, title and interest in the
said application and invention therein disclosed for the United States and
foreign countries, and all rights of priority resulting from the filing said
United States application, and I request the Commissioner of Patents to
issue any Letters Patent granted upon the invention set forth in said
application to **AOS** its successors and assigns; and I hereby agree that
AOS may apply for foreign Letters Patent on said invention and I will
execute all papers necessary in connection with the United States and
foreign applications when called upon to do so by

CITY AND

Signed and Sealed at Sunnyvale

DATE

on Jan. 19, 2012



HAMZA YILMAZ

ASSIGNMENT

INVENTOR AND CITY Whereas, I, ANUP BHALLA of 1406 Block Drive Santa Clara, CA 95050, USA

have invented:

TITLE: NANO MOSFET WITH TRENCH BOTTOM OXIDE SHIELDED AND THIRD DIMENSIONAL P-BODY CONTACT

DATE INVENTOR SIGNED THE DECLARATION and executed a United States patent application therefor on _____, 2012. Said assignor hereby authorize and request their attorney, Joshua D. Isenberg, of 809 Corporate Way, Fremont, California, to insert here in parentheses (Application number 15/680,712, file August 18, 2017) the filing date and application number of said application when known.

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Now therefore for a valuable consideration, receipt whereof is hereby acknowledged, I, the above named, hereby sell, assign, and transfer to AOS, its successors and assigns, the entire right, title and interest in the said application and invention therein disclosed for the United States and foreign countries, and all rights of priority resulting from the filing said United States application, and I request the Commissioner of Patents to issue any Letters Patent granted upon the invention set forth in said application to AOS its successors and assigns; and I hereby agree that AOS may apply for foreign Letters Patent on said invention and I will execute all papers necessary in connection with the United States and foreign applications when called upon to do so by

CITY AND Signed and Sealed at SUNNYVALE

DATE on Jan 30, 2012

Anup Bhalla
ANUP BHALLA

ASSIGNMENT

**INVENTOR
AND CITY**

Whereas, I, **YEEHENG LEE** of 1436 Bellemeade Street
San Jose, CA 95131, USA

have invented:

TITLE:

**NANO MOSFET WITH TRENCH BOTTOM OXIDE SHIELDED
AND THIRD DIMENSIONAL P-BODY CONTACT**

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AOS may apply for foreign Letters Patent on said invention and I will
execute all papers necessary in connection with the United States and
foreign applications when called upon to do so by

CITY AND

Signed and Sealed at Sunnyvale, CA

DATE

on 1/30, 2012



YEEHENG LEE

ASSIGNMENT

INVENTOR AND CITY Whereas, I, **DANIEL NG** of **3887 Via Montalvo Campbell, CA 95008, USA**

have invented:

TITLE: **NANO MOSFET WITH TRENCH BOTTOM OXIDE SHIELDED AND THIRD DIMENSIONAL P-BODY CONTACT**

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CITY AND Signed and Sealed at *Sunnyvale*

DATE on *11/31*, 2012

[Signature]
DANIEL NG

ASSIGNMENT

**INVENTOR
AND CITY**

Whereas, I, **JONGOH KIM** of 5337, NW Paseo Ter.,
Portland, Oregon 97229, USA

have invented:

TITLE:

**NANO MOSFET WITH TRENCH BOTTOM OXIDE SHIELDED
AND THIRD DIMENSIONAL P-BODY CONTACT**

**DATE INVENTOR
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execute all papers necessary in connection with the United States and
foreign applications when called upon to do so by

CITY AND

Signed and Sealed at Portland, OR, USA

DATE

on Jan/31st, 2012



JONGOH KIM

ASSIGNMENT

**INVENTOR
AND CITY**

Whereas, I, **JI PAN** of 1758 Cape Coral Dr.
San Jose, CA 95133, USA

have invented:

TITLE:

**NANO MOSFET WITH TRENCH BOTTOM OXIDE SHIELDED
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application to **AOS** its successors and assigns; and I hereby agree that
AOS may apply for foreign Letters Patent on said invention and I will
execute all papers necessary in connection with the United States and
foreign applications when called upon to do so by

CITY AND

Signed and Sealed at Sunnyvale

DATE

on 2/1, 2012



JIPAN

ASSIGNMENT

**INVENTOR
AND CITY**

Whereas, I, **DANIEL CALAFUT** of 188 Ballatore Court
San Jose, CA 95134, USA

have invented:

TITLE:

**NANO MOSFET WITH TRENCH BOTTOM OXIDE SHIELDED
AND THIRD DIMENSIONAL P-BODY CONTACT**

**DATE INVENTOR
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application to **AOS** its successors and assigns; and I hereby agree that
AOS may apply for foreign Letters Patent on said invention and I will
execute all papers necessary in connection with the United States and
foreign applications when called upon to do so by

CITY AND

Signed and Sealed at SUNNYVALE

DATE

on FEB, 01, 2012.



DANIEL CALAFUT

ASSIGNMENT

INVENTOR AND CITY Whereas, I, **MADHUR BOBDE** of 1602 Goldfinch Way Sunnyvale CA 94087, USA

have invented:

TITLE: **NANO MOSFET WITH TRENCH BOTTOM OXIDE SHIELDED AND THIRD DIMENSIONAL P-BODY CONTACT**


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CITY AND Signed and Sealed at Sunnyvale, CA

DATE on Feb 2nd, 2012



MADHUR BOBDE